

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

James Thomas Doyle et al.

Appln. No.: New (Div. of 10/272,035)

Filed: Herewith

For: MOS TRANSISTOR WITH SERRATED
GATE STRUCTURES (as amended)

Group Art Unit: Unknown

Examiner: Unknown

PRELIMINARY AMENDMENT

INTRODUCTORY COMMENTSMail Stop Patent Application
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Please amend the above-identified application as indicated on the following pages.

Amendments to the Specification which begin on page 2 of this paper;

Amendments to the Claims are reflected in the listing of claims which begins on page 5 of this paper; and

Remarks which begin on page 11 of this paper.